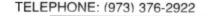
20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A.

## **Triacs** Bidirectional Triode Thyristors

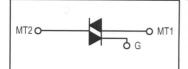
... designed primarily for full-wave ac control applications, such as light dimmers, motor controls, heating controls and power supplies.

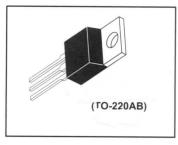
- Blocking Voltage to 600 Volts
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- T2800 Four Quadrant Gating











#### MAXIMUM RATINGS (TJ = 25°C unless otherwise noted.)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage <sup>(1)</sup> (T <sub>J</sub> = –40 to +100°C, Gate Open)	VDRM		Volts
T2800 B D M		200 400 600	
RMS On-State Current (T <sub>C</sub> = +80°C) (Conduction Angle = 360°)	<sup>I</sup> T(RMS)	8	Amps
Peak Non-repetitive Surge Current (One Full Cycle, 60 Hz, T <sub>J</sub> = +80°C)	ITSM	100	Amps
Circuit Fusing (t = 8.3 ms)	l <sup>2</sup> t	40	A <sup>2</sup> s
Peak Gate Power (Pulse Width = 1 µs)	PGM	16	Watts
Average Gate Power	PG(AV)	0.35	Watt
Peak Gate Trigger Current (Pulse Width = 1 μs)	IGTM	4	Amps
Operating Junction Temperature Range	TJ	-40 to +100	°C
Storage Temperature Range	T <sub>stg</sub>	-40 to +150	°C

 Characteristic
 Symbol
 Max
 Unit

 Thermal Resistance, Junction to Case
 R<sub>θJC</sub>
 2.2
 °C/W

1. V<sub>DRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

# N J S

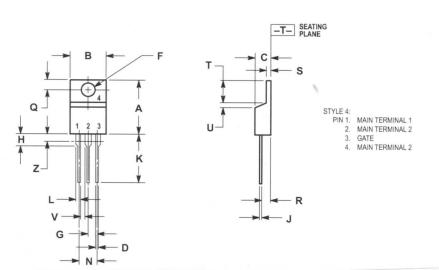
### **Quality Semi-Conductors**

### **T2800 SERIES**

ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Blocking Current $T_C = 25^{\circ}C$ $(V_D = Rated V_{DRM}, Gate Open)$ $T_C = 100^{\circ}C$	IDRM		_	10 2	μA mA
Peak On-State Voltage (Either Direction)* (I <sub>T</sub> = 30 A Peak)	VTM	-	1.7	2	Volts
Gate Trigger Current (Continuous dc) (V <sub>D</sub> = 12 Vdc, R <sub>L</sub> = 12 Ohms) MT2(+), G(+) T2800 MT2(+), G(-) T2800 MT2(-), G(-) T2800 MT2(-), G(+) T2800	lgt		10 20 15 30	25 60 25 60	mA
Gate Trigger Voltage (Continuous dc) (All Polarities) (V <sub>D</sub> = 12 Vdc, R <sub>L</sub> = 100 Ohms) (R <sub>L</sub> = 125 Ohms, V <sub>D</sub> = V <sub>DRM</sub> , T <sub>C</sub> = 100°C)	VGT	0.2	1.25	2.5	Volts
Holding Current (Either Direction) (V <sub>D</sub> = 12 Vdc, Gate Open) T2800	Ч	-	15	30	mA
Gate Controlled Turn-On Time (V <sub>D</sub> = Rated V <sub>DRM</sub> , I <sub>T</sub> = 10 A, I <sub>GT</sub> = 80 mA, Rise Time = 0.1 μs)	tgt	-	1.6	—	μs
Critical Rate-of-Rise of Commutation Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , I <sub>T</sub> (RMS) = 8 A, Commutating di/dt = 4.1 A/ms, Gate Unenergized, T <sub>C</sub> = 80°C)	dv/dt(c)	-	10	-	V/µs
Critical Rate-of-Rise of Off-State Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , Exponential Voltage Rise, Gate Open, T <sub>C</sub> = 100°C) T2800 B D M	dv/dt	100  60			V/µs

\*Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle  $\leq$  2%.



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
н	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.055	1.15	1.39
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045		1.15	
Z		0.080		2.04